



HIGH DENSITY MOUNTING PHOTOTRANSISTOR OPTICALLY COUPLED ISOLATORS

APPROVALS

- UL recognised, File No. E91231

'X' SPECIFICATION APPROVALS

- VDE 0884 pending
- Certified to EN60950 by the following Test Bodies :-
Nemko - Certificate No. P96102022
Fimko - Registration No. 192313-01..25
Semko - Reference No. 9639052 01
Demko - Reference No. 305969

DESCRIPTION

The PS2501-1, PS2501-2, PS2501-4 series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photo transistors in space efficient dual in line plastic packages.

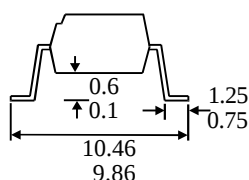
FEATURES

- Options :-
10mm lead spread - add G after part no.
Surface mount - add SM after part no.
Tape&reel - add SMT&R after part no.
- High Current Transfer Ratio (80% min)
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- High BV_{CEO} (80Vmin)
- All electrical parameters 100% tested
- Custom electrical selections available

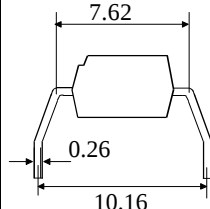
APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances

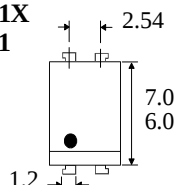
OPTION SM SURFACE MOUNT



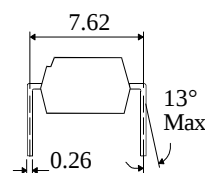
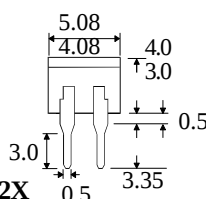
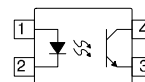
OPTION G



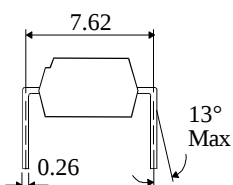
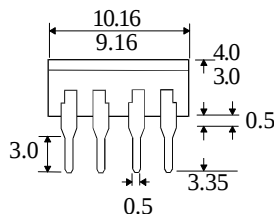
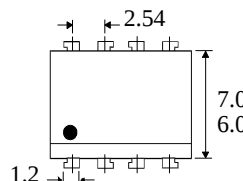
PS2501-1X PS2501-1



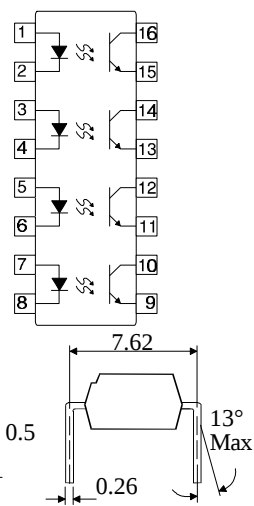
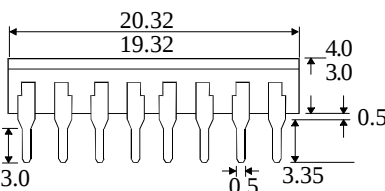
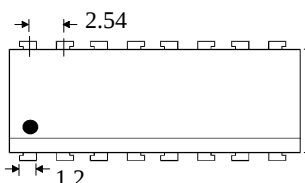
Dimensions in mm



PS2501-2X PS2501-2



PS2501-4X PS2501-4



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ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature _____ -55°C to + 125°C
Operating Temperature _____ -55°C to + 100°C
Lead Soldering Temperature
(1/16 inch (1.6mm) from case for 10 secs) 260°C

INPUT DIODE

Forward Current _____ 50mA
Reverse Voltage _____ 6V
Power Dissipation _____ 70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO} _____ 80V
Emitter-collector Voltage BV_{ECO} _____ 6V
Power Dissipation _____ 150mW

POWER DISSIPATION

Total Power Dissipation _____ 200mW
(derate linearly 2.67mW/°C above 25°C)

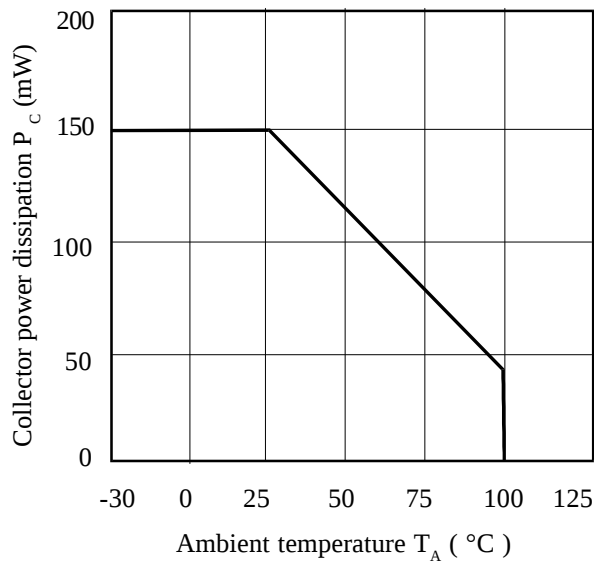
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)	5	1.2	1.4	V	$I_F = 20\text{mA}$ $I_R = 5\mu\text{A}$ $V_R = 5\text{V}$
	Reverse Voltage (V_R)			5	V	
	Reverse Current (I_R)				μA	
Output	Collector-emitter Breakdown (BV_{CEO}) (Note 2)	80		100	V	$I_C = 1\text{mA}$ $I_E = 100\mu\text{A}$ $V_{CE} = 40\text{V}$
	Emitter-collector Breakdown (BV_{ECO})	6			V	
	Collector-emitter Dark Current (I_{CEO})				nA	
Coupled	Current Transfer Ratio (CTR) (Note 2) PS2501-1,PS2501-2,PS2501-4 GR	80		600	%	$5\text{mA } I_F, 5\text{V } V_{CE}$ $5\text{mA } I_F, 5\text{V } V_{CE}$
		100		300	%	
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$			0.3	V	$10\text{mA } I_F, 2\text{mA } I_C$
	Input to Output Isolation Voltage V_{ISO}	5300			V_{RMS}	See note 1 See note 1
		7500			V_{PK}	
	Input-output Isolation Resistance R_{ISO}	5×10^{10}			Ω	$V_{IO} = 500\text{V}$ (note 1)
	Output Rise Time t_r			4	μs	$V_{CE} = 2\text{V}$, $I_C = 2\text{mA}$, $R_L = 100\Omega$
	Output Fall Time t_f			3	μs	

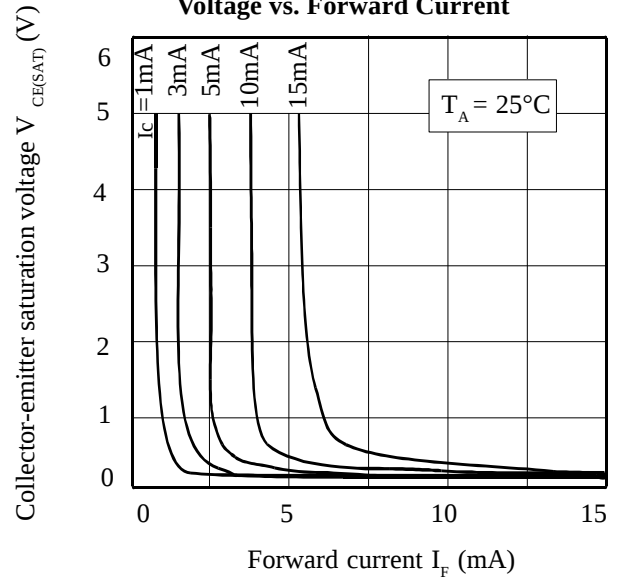
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

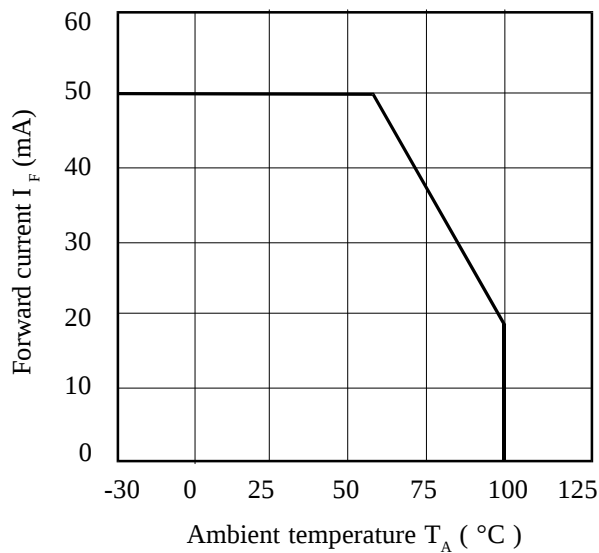
Collector Power Dissipation vs. Ambient Temperature



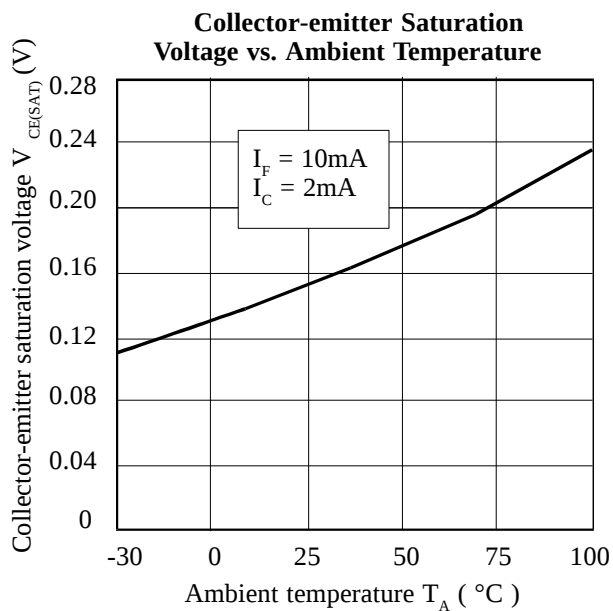
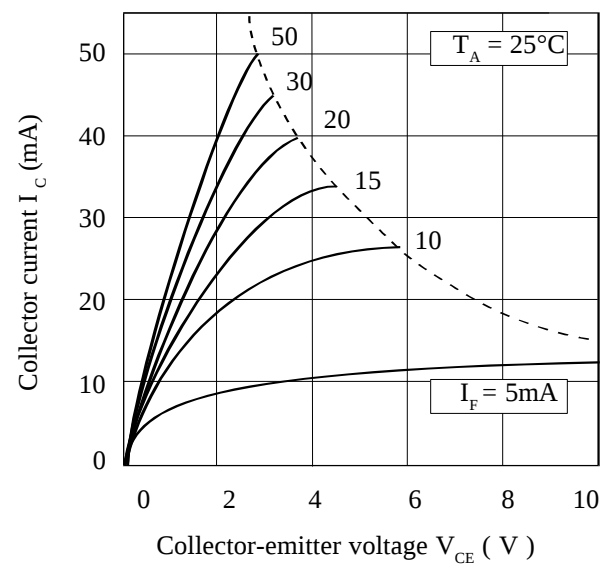
Collector-emitter Saturation Voltage vs. Forward Current



Forward Current vs. Ambient Temperature



Collector Current vs. Collector-emitter Voltage



Current Transfer Ratio vs. Forward Current

